Product data sheet

1. General description

The 74LVC1G332 provides one 3-input OR function.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V applications.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101-C exceeds 1000 V
- ± 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Ordering information 3.

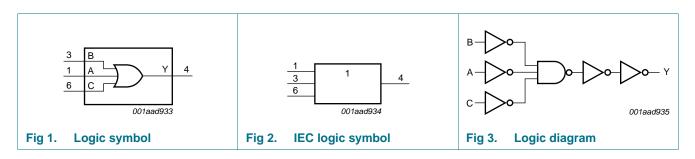
Table 1. Ordering information								
Type number	Package							
	Temperature Name range		Description	Version				
74LVC1G332GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74LVC1G332GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				
74LVC1G332GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74LVC1G332GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891				
74LVC1G332GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1G332GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				

Marking 4.

Table 2. Marking	
Type number	Marking code ^[1]
74LVC1G332GW	YG
74LVC1G332GV	YG
74LVC1G332GM	YG
74LVC1G332GF	YG
74LVC1G332GN	YG
74LVC1G332GS	YG

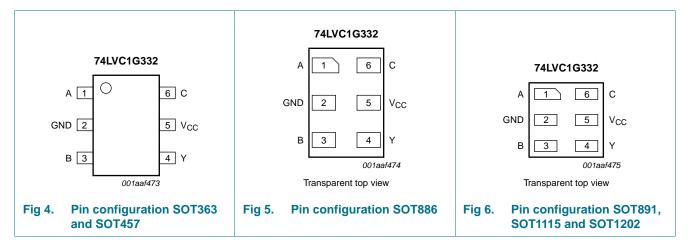
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

Functional diagram 5.



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description		
Symbol		Pin	Description
А		1	data input
GND		2	ground (0 V)
В		3	data input
Y		4	data output
V _{CC}		5	supply voltage
С		6	data input

7. Functional description

Table 4. Function table^[1]

Input	Output		
Α	В	C	Y
Н	Х	Х	Н
Х	Н	Х	Н
Х	Х	Н	Н
L	L	L	L

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		JJII /	0	10	,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
Ι _{ΟΚ}	output clamping current	$V_{O} > V_{CC}$ or $V_{O} < 0$ V	-	±50	mA
Vo	output voltage	Active mode	[1][2] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW
T _{stg}	storage temperature		-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When V_{CC} = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		$V_{CC} = 0 V$; Power-down mode	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$	-	-	10	ns/V

Single 3-input OR gate

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol P	Parameter	Conditions	-40 °	°C to +8	5 °C	–40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
ViH	HIGH-level	V _{CC} = 1.65 V to 1.95 V	$0.65V_{CC}$	-	-	0.65V _{CC}	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V	0.7V _{CC}	-	-	$0.7V_{CC}$	-	V
VIL	LOW-level	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
/ _{ОН}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
output vo	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V	$V_{CC}-0.1$	-	-	$V_{CC}-0.1$	-	V
		$I_0 = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	0.95	-	V
		$I_0 = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	1.7	-	V
		$I_0 = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	1.9	-	V
		$I_0 = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.3	-	-	2.0	-	V
		$I_0 = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	3.4	-	V
/ _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	-	0.1	V
		$I_0 = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.70	V
		$I_0 = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	-	0.45	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	-	0.4	-	0.60	V
		$I_0 = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.80	V
		$I_0 = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	-	0.80	V
I	input leakage current	$V_{CC} = 0 V$ to 5.5 V; V _I = 5.5 V or GND	-	±0.1	±5	-	±100	μΑ
OFF	power-off leakage current	V_{CC} = 0 V; V ₁ or V ₀ = 5.5 V	-	±0.1	±10	-	±200	μΑ
CC	supply current	V_{CC} = 1.65 V to 5.5 V; V _I = V _{CC} or GND; I _O = 0 A	-	0.1	10	-	200	μA
Alcc	additional supply current	per pin; $V_{CC} = 2.3 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}$	-	5	500	-	5000	μA
Ci	input capacitance	$V_{CC} = 3.3 \text{ V}; \text{ V}_{I} = \text{GND to}$ V_{CC}	-	3	-	-	-	pF

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 8.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to +125 °C		Unit
				Min	Typ <mark>[1]</mark>	Мах	Min	Max	
t _{pd}	propagation delay	A, B and C to Y; see Figure 7	[2]						
	V_{CC} = 1.65 V to 1.95 V		1.5	4.7	17.2	1.5	21.5	ns	
		V_{CC} = 2.3 V to 2.7 V		1.0	3.0	6.2	1.0	7.8	ns
		V _{CC} = 2.7 V		1.0	3.0	6.0	1.0	7.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.0	2.6	4.8	1.0	6.2	ns
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		1.0	1.9	3.5	1.0	4.4	ns
C_{PD}	power dissipation capacitance	$V_{\rm I}$ = GND to $V_{CC};V_{CC}$ = 3.3 V	[3]	-	12	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $\mathsf{P}_{\mathsf{D}} = C_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_i \times \mathsf{N} + \sum (C_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}{}^2 \times \mathsf{f}_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

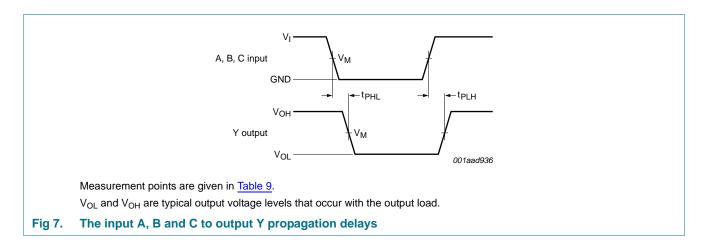
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of outputs.

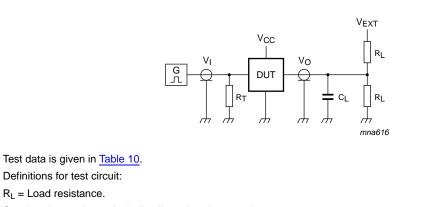
12. AC waveforms



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74LVC1G332

Table 9. Measurement points						
Supply voltage	Input	Output				
V _{CC}	V _M	V _M				
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}				
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}				
2.7 V	1.5 V	1.5 V				
3.0 V to 3.6 V	1.5 V	1.5 V				
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}				



 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input	Input		Load		
V _{cc}	VI	$t_r = t_f$	CL	RL	t _{PLH} , t _{PHL}	
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open	
2.3 V to 2.7 V	V _{CC}	\leq 2.0 ns	30 pF	500 Ω	open	
2.7 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open	
3.0 V to 3.6 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open	
4.5 V to 5.5 V	V _{CC}	\leq 2.5 ns	50 pF	500 Ω	open	

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Single 3-input OR gate

13. Package outline

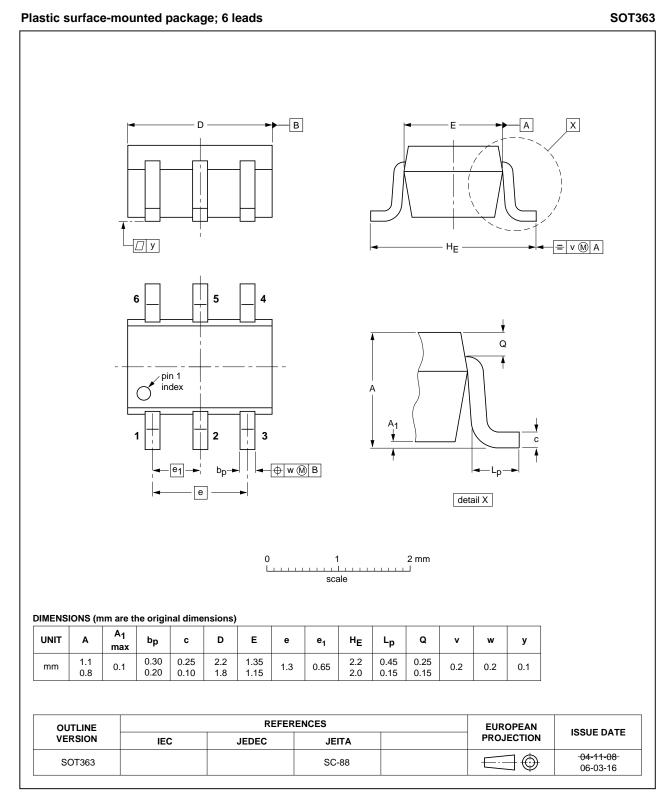


Fig 9. Package outline SOT363 (SC-88)

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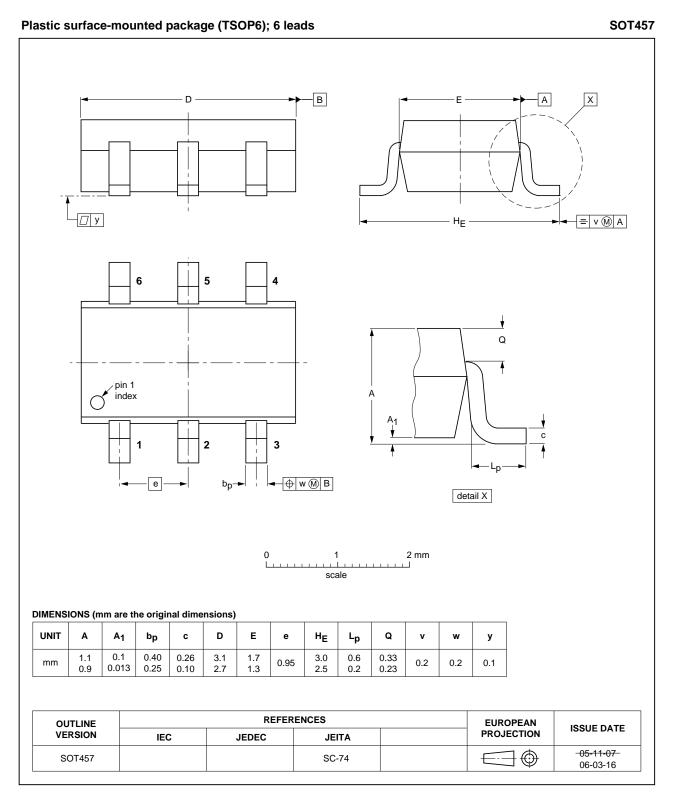
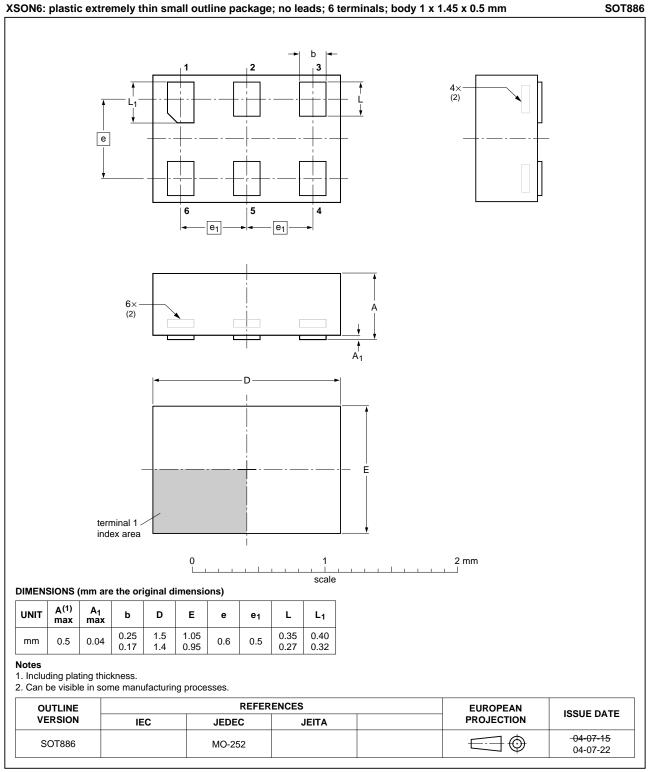


Fig 10. Package outline SOT457 (SC-74)

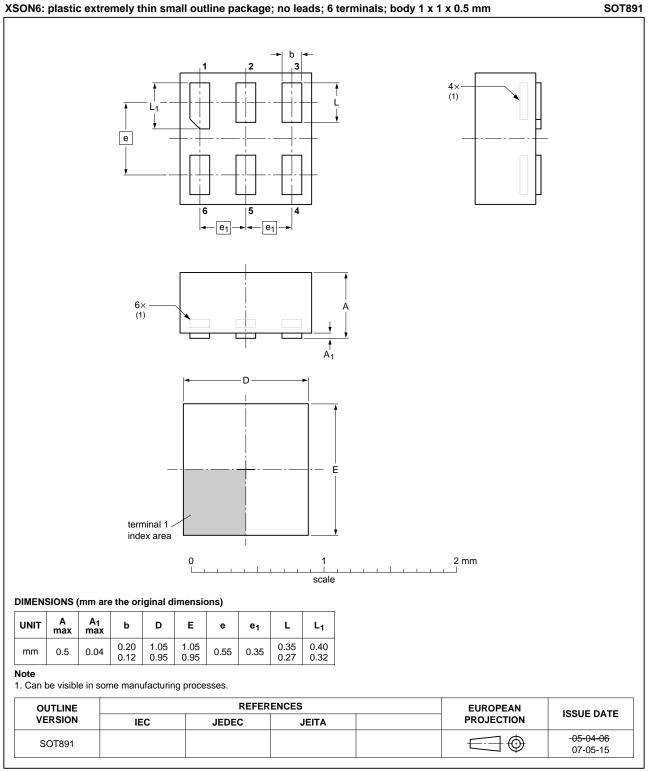
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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

Fig 11. Package outline SOT886 (XSON6)

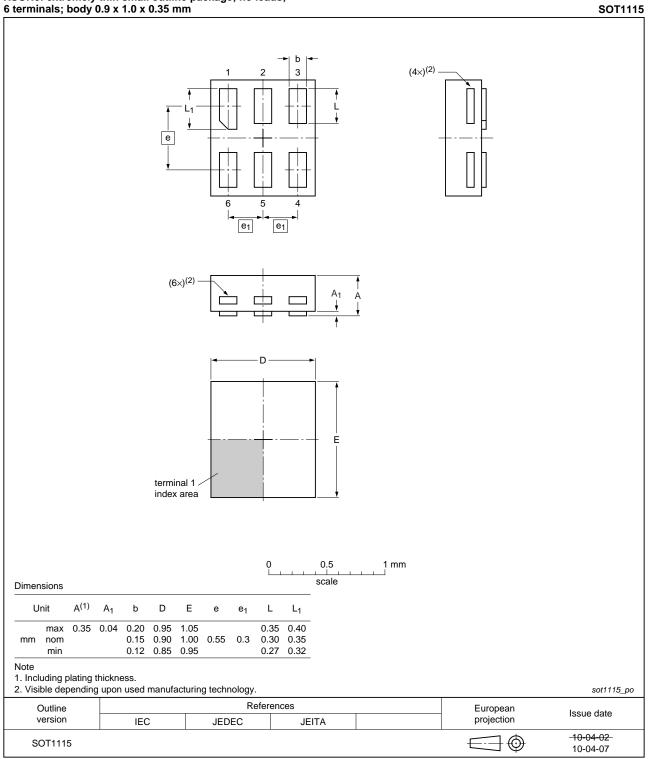
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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

Fig 12. Package outline SOT891 (XSON6)

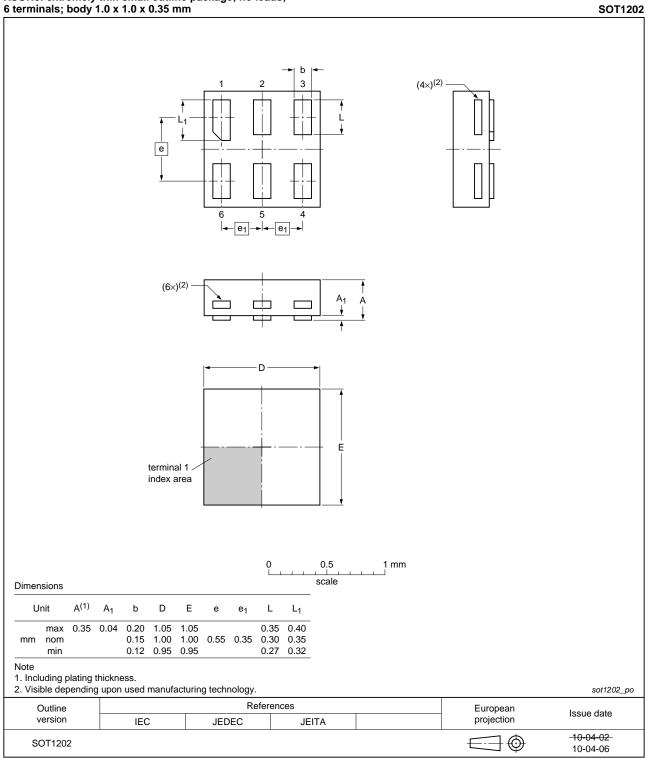
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XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 13. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 14. Package outline SOT1202 (XSON6)

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14. Abbreviations

Acronym CDM CMOS DUT ESD	Description Charged Device Model Complementary Metal Oxide Semiconductor
CMOS DUT	
DUT	Complementary Metal Oxide Semiconductor
-	
ESD	Device Under Test
	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 12.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G332 v.4	20111206	Product data sheet	-	74LVC1G332 v.3
Modifications:	 Legal pages 	s updated.		
74LVC1G332 v.3	20101026	Product data sheet	-	74LVC1G332 v.2
74LVC1G332 v.2	20070719	Product data sheet	-	74LVC1G332 v.1
74LVC1G332 v.1	20061011	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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